

SBYV26A THRU SBYV26G

SINTERED GLASS JUNCTION SURFACE MOUNTED RECTIFIER

VOLTAGE: 200 to 1400V

CURRENT: 1.0A



FEATURE

Ideal for surface mount automotive applications
High temperature metallurgically bonded construction
Sintered glass cavity free junction
Capability of meeting environmental standard of
MIL-S-19500
High temperature soldering guaranteed
350°C /10sec/0.375"lead length at 5 lbs tension
Operate at Ta =55°C with no thermal run away
Typical Ir<0.1μA

MECHANICAL DATA

Terminal: Plated axial leads solderable per MIL-STD 202E,
Method 208C

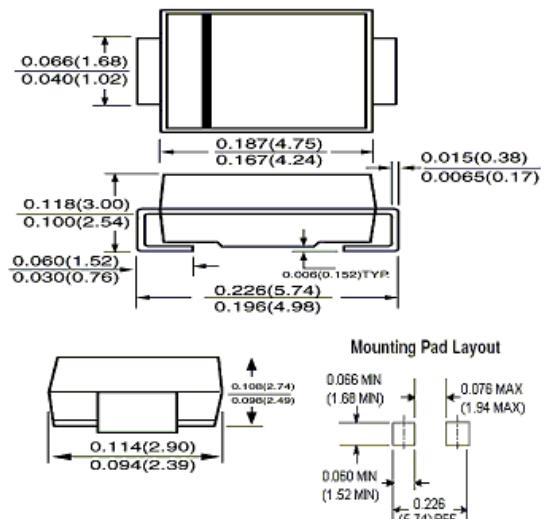
Case: Molded with UL-94 Class V-0 recognized Flame
Retardant Epoxy

Polarity: color band denotes cathode

Mounting position: any

Marking: V26A V26B V26C V26D V26E V26F V26G

GF1/ DO-214BA



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

	SYMBOL	SBYV 26A	SBYV 26B	SBYV 26C	SBYV 26D	SBYV 26E	SBYV 26F	SBYV 26G	units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	200	400	600	800	1000	1200	1400	V
Maximum RMS Voltage	V _{RMS}	140	280	420	560	700	840	980	V
Maximum DC blocking Voltage	V _{DC}	200	400	600	800	1000	1200	1400	V
Reverse avalanche breakdown voltage at IR = 0.1 mA	V _{(BR)R}	300 min	500 min	700 min	900 min	1100 min	1300 min	1500 min	V
Maximum Average Forward Rectified current T _L =120°C	I _{FAV}					1.0			A
Non-repetitive Peak Forward Current at t=10ms half sine wave	I _{FSM}				30				A
Maximum Forward Voltage at rated Forward Current	V _F			2.5		2.15			V
Non-repetitive peak reverse avalanche energy (Note 1)	E _{RSR}			10					mJ
Maximum DC Reverse Current Ta =25°C at rated DC blocking voltage Ta =165°C	I _R			5.0		150.0			μA
Maximum Reverse Recovery Time (Note 2)	T _{rr}		30		75		150		nS
Diode Capacitance (Note 3)	C _j			15.0					pF
Typical Thermal Resistance (Note 4)	R _{th(ja)}			100					°C /W
Storage and Operating Junction Temperature	T _{stg, T_j}			-65 to +175					°C

Note: 1. R=400mA; T_j=T_{jmax} prior to surge; inductive load switched off

2. Reverse Recovery Condition If =0.5A, I_r =1.0A, I_{rr} =0.25A

3. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc

4. Thermal Resistance from Junction to Ambient and from junction to lead, P.C.B. Mounted on 0.2×0.2" (5.0×5.0mm) copper pad areas

RATINGS AND CHARACTERISTIC CURVES SBYV26A THRU SBYV26G

Fig. 1 – Maximum Forward Current Derating Curve

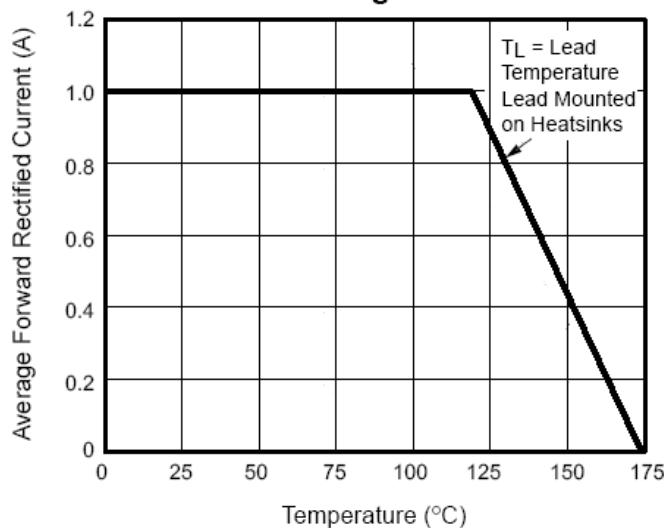


Fig. 3 – Typical Instantaneous Forward Voltage Characteristics

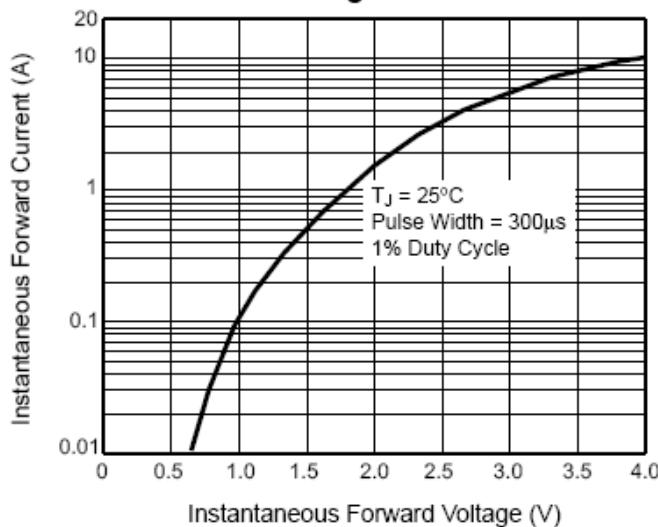


Fig. 5 – Typical Junction Capacitance

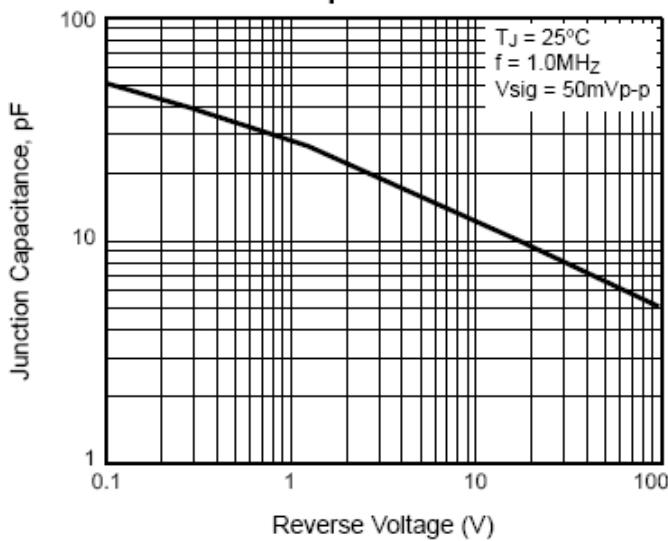


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

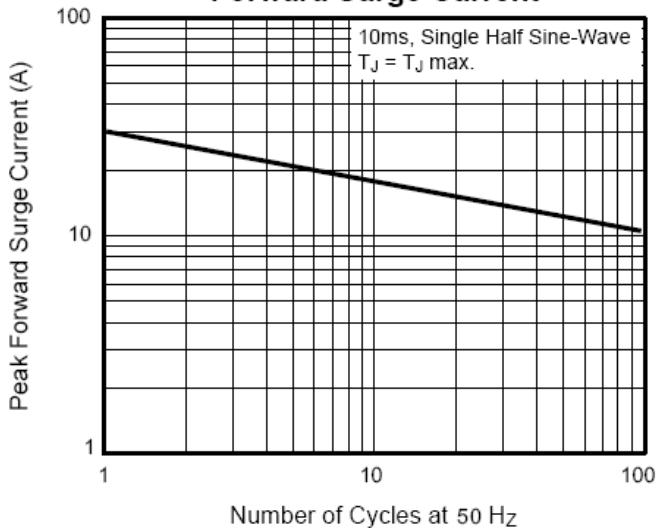


Fig. 4 – Typical Reverse Leakage Characteristics

